Thyristor Semiconductor Device - Page 1 of 1



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## **Inclosure Material:**

Metal

# **Overall Length:**

Between 0.240 inches and 0.260 inches

## **Terminal Length:**

Between 0.500 inches and 0.750 inches

## **Overall Diameter:**

Between 0.335 inches and 0.370 inches

### **Function For Which Designed:**

Reverse blocking

### **Internal Configuration:**

Junction contact

### **Electrode Internally-electrically Connected To Case:**

Anode

#### **Mounting Method:**

# Terminal **Terminal Circle Diameter:**

0.200 inches

## **Features Provided:**

Quality assurance level tx and burn in and hermetically sealed case

### **Semiconductor Material:**

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, peak and 150.0 nonrepetitive peak reverse voltage, peak total value

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnpn

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Terminal Type And Quantity:**

3 uninsulated wire lead

### **Specification Data:**

81349-mil-s-19500/276 government specification

#### Shelf Life:

N/a

Unit Of Measure:

## Demilitarization:

No

Fiig:

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